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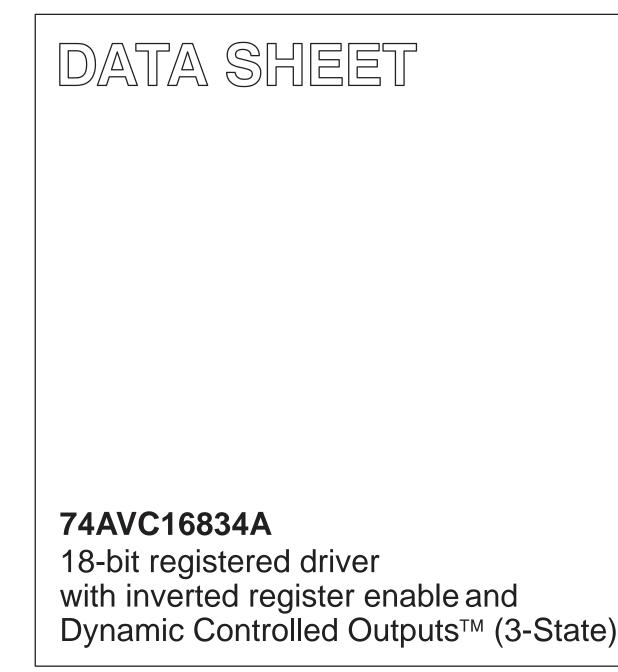
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Team Nexperia

INTEGRATED CIRCUITS



Product data Supersedes data of 2000 Jul 25 2002 Sep 11



Philips Semiconductors

74AVC16834A

FEATURES

- Wide supply voltage range of 1.2 V to 3.6 V
- Complies with JEDEC standard no. 8-1A/5/7
- CMOS low power consumption
- Input/output tolerant up to 3.6 V
- DCO (Dynamic Controlled Output) circuit dynamically changes output impedance, resulting in noise reduction without speed degradation
- \bullet Low inductance multiple V_{CC} and GND pins for minimum noise and ground bounce
- Power off disables 74AVC16834A outputs, permitting Live Insertion
- Integrated input diodes to minimize input overshoot and undershoot
- Full PC133 solution provided when used with PCK2509S or PCK2510S and CBT16292

DESCRIPTION

The 74AVC16834A is a 18-bit universal bus driver. Data flow is controlled by output enable (OE), latch enable (LE) and clock inputs (CP).

This product is designed to have an extremely fast propagation delay and a minimum amount of power consumption.

To ensure the high-impedance state during power up or power down, OE should be tied to V_{CC} through a pullup resistor (Live Insertion).

A Dynamic Controlled Output (DCO) circuitry is implemented to support termination line drive during transient. See the graphs on page 9 for typical curves.

PIN CONFIGURATION

	<u> </u>	
NC 1	56 GND	
NC 2	55 NC	
Y ₀ 3	54 A ₀	
GND 4	53 GND	
Y ₁ 5	52 A ₁	
Y ₂ 6	51 A ₂	
V _{CC} 7	50 V _{CC}	
Y ₃ 8	49 A ₃	
Y ₄ 9	48 A ₄	
Y ₅ 10	47 A ₅	
GND 11	46 GND	
Y ₆ 12	45 A ₆	
Y ₇ 13	44 A ₇	
Y ₈ 14	43 A ₈	
Y ₁₀ 16	41 A ₁₀	
Y ₁₁ 17	40 A ₁₁	
GND 18	39 GND	
Y ₁₂ 19	38 A ₁₂	
Y ₁₃ 20	37 A ₁₃	
Y ₁₄ 21	36 A ₁₄	
V _{CC} 22	35 V _{CC}	
Y ₁₅ 23	34 A ₁₅	
Y ₁₆ 24	33 A ₁₆	
GND 25	32 GND	
Y ₁₇ 26	31 A ₁₇	
<u>OE</u> 27	30 CP	
LE 28	29 GND	SH00156
L		2.100100

QUICK REFERENCE DATA

GND = 0 V; $T_{amb} = 25 \text{ °C}$; $t_r = t_f \le 2.0 \text{ ns}$; $C_L = 30 \text{ pF}$.

SYMBOL	PARAMETER	CONDITIO	CONDITIONS		
t _{PHL} /t _{PLH}	Propagation delay An to Yn	V _{CC} = 1.8 V V _{CC} = 2.5 V V _{CC} = 3.3 V		2.6 2.0 1.7	ns
t _{PHL} /t _{PLH}	Propagation delay LE to Yn; CP to Yn	V _{CC} = 1.8 V V _{CC} = 2.5 V V _{CC} = 3.3 V		2.9 2.3 1.9	ns
Cl	Input capacitance			5.0	pF
C Dewer dissinction conscitance per huffer		$V_1 = GND$ to V_{CC}^1	Outputs enabled	25	pF
C _{PD}	Power dissipation capacitance per buffer		Output disabled	6	рг

NOTES:

1. C_{PD} is used to determine the dynamic power dissipation (P_D in μW):

 $P_{D} = C_{PD} \times V_{CC}^{2} \times f_{i} + \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) \text{ where: } f_{i} = \text{input frequency in MHz; } C_{L} = \text{output load capacitance in pF;}$ $f_{o} = \text{output frequency in MHz; } V_{CC} = \text{supply voltage in V; } \Sigma (C_{L} \times V_{CC}^{2} \times f_{o}) = \text{sum of outputs.}$

ORDERING INFORMATION

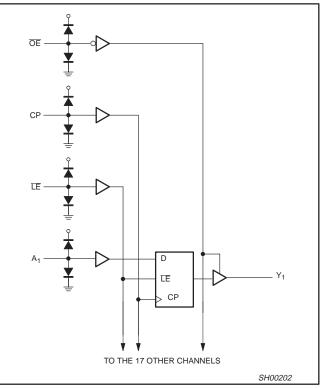
PACKAGES	TEMPERATURE RANGE	ORDER CODE	DRAWING NUMBER
56-Pin Plastic 0.5 mm pitch TSSOP	–40°C to +85°C	74AVC16834ADGG	SOT364-1
56-Pin Plastic 0.4 pitch TSSOP (TVSOP)	–40°C to +85°C	74AVC16834ADGV	SOT481-2

74AVC16834A

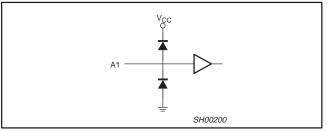
PIN DESCRIPTION

PIN NUMBER	SYMBOL	NAME AND FUNCTION
1, 2, 55	NC	No connection
3, 5, 6, 8, 9, 10, 12, 13, 14, 15, 16, 17, 19, 20, 21, 23, 24, 26	Y_0 to Y_{17}	Data outputs
4, 11, 18, 25, 32, 39, 46, 53, 56	GND	Ground (0 V)
7, 22, 35, 50	V _{CC}	Positive supply voltage
27	ŌĒ	Output enable input (active LOW)
28	LE	Latch enable input (active LOW)
30	CP	Clock input
54, 52, 51, 49, 48, 47, 45, 44, 43, 42, 41, 40, 38, 37, 36, 34, 33, 31	A_0 to A_{17}	Data inputs

LOGIC SYMBOL

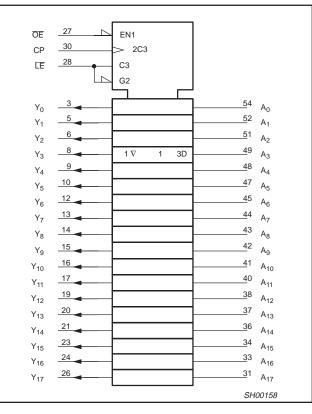


TYPICAL INPUT (DATA OR CONTROL)



74AVC16834A

LOGIC SYMBOL (IEEE/IEC)



FUNCTION TABLE

	INPUTS								
OE	LE	СР	Α	OUTPUTS					
Н	Х	Х	Х	Z					
L	L	Х	L	L					
L	L	Х	Н	Н					
L	Н	\uparrow	L	L					
L	Н	\uparrow	Н	Н					
L	Н	Н	Х	Y ₀ 1					
L	Н	L	Х	Y ₀ ²					

HIGH voltage level н =

L = LOW voltage level

Don't care =

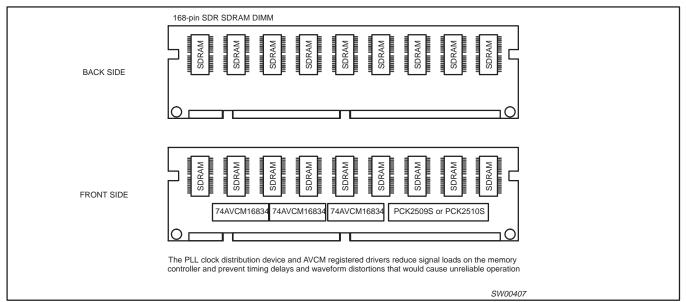
X Z ↑ = High impedance "off" state

LOW-to-HIGH level transition =

NOTES:

1. Output level before the indicated steady-state input conditions were established, provided that CP is high before LE goes low.

2. Output level before the indicated steady-state input conditions were established.



74AVC16834A

RECOMMENDED OPERATING CONDITIONS

SYMBOL	PARAMETER	CONDITIONS	MIN	MAX	UNIT	
V _{CC}	DC supply voltage (according to JEDEC Low Voltage Standards)		1.65 2.3 3.0	1.95 2.7 3.6	V	
	DC supply voltage (for low voltage applications)		1.2	3.6	V	
VI	DC Input voltage range		0	3.6	V	
	DC output voltage range; output 3-State		0	3.6		
Vo	DC output voltage range; output HIGH or LOW state		0	V _{CC}	V	
T _{amb}	Operating free-air temperature range		-40	+85	°C	
		V _{CC} = 1.65 to 2.3 V	0	30	1	
t _r , t _f	Input rise and fall times	V _{CC} = 2.3 to 3.0 V	0	20	ns/V	
		V _{CC} = 3.0 to 3.6 V	0	10	1	

ABSOLUTE MAXIMUM RATINGS

In accordance with the Absolute Maximum Rating System (IEC 134). Voltages are referenced to GND (ground = 0 V).

SYMBOL	PARAMETER	CONDITIONS	RATING	UNIT
V _{CC}	DC supply voltage		-0.5 to +4.6	V
I _{IK}	DC input diode current	V ₁ <0	-50	mA
VI	DC input voltage	For all inputs ¹	-0.5 to 4.6	V
I _{ОК}	DC output diode current	$V_{O} > V_{CC} \text{ or } V_{O} < 0$	±50	mA
Vo	DC output voltage; output 3-State	Note 1	-0.5 to 4.6	V
Vo	DC output voltage; output HIGH or LOW state	Note 1	–0.5 to V _{CC} +0.5	V
Ι _Ο	DC output source or sink current	$V_{O} = 0$ to V_{CC}	±50	mA
I _{GND} , I _{CC}	DC V _{CC} or GND current		±100	mA
T _{stg}	Storage temperature range		–65 to +150	°C
P _{TOT}	Power dissipation per package –plastic thin-medium-shrink (TSSOP)	For temperature range: -40 to +125 °C above +55 °C derate linearly with 8 mW/K	600	mW

NOTE:

1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

Product data

DC ELECTRICAL CHARACTERISTICS

Over recommended operating conditions. Voltage are referenced to GND (ground = 0 V).

			LIMITS				
SYMBOL	PARAMETER	TEST CONDITIONS	Temp = −40°C to +85°C				
			MIN	TYP ¹	MAX	1	
		V _{CC} = 1.2 V	V _{CC}	-	-		
V		V _{CC} = 1.65 to 1.95 V	0.65V _{CC}	0.9	-		
VIH	V _{IH} HIGH level Input voltage	V _{CC} = 2.3 to 2.7 V	1.7	1.2	-	ľ	
		V _{CC} = 3.0 to 3.6 V	2.0	1.5	-		
		V _{CC} = 1.2 V	-	-	GND		
V	LOW level Input voltage	V _{CC} = 1.65 to 1.95 V	-	0.9	$0.35V_{CC}$		
VIL	LOw level input voltage	V _{CC} = 2.3 to 2.7 V	-	1.2	0.7	ľ	
		V _{CC} = 3.0 to 3.6 V	-	1.5	0.8	1	
		V_{CC} = 1.65 to 3.6V; V_{I} = V_{IH} or $V_{IL};$ I_{O} = –100 μA	V _{CC} -0.20	V _{CC}	-		
V _{OH}	V _{OH} HIGH level output voltage	V_{CC} = 1.65 V; V_I = V_{IH} or V_{IL} ; I_O = -4 mA	V _{CC} -0.45	V _{CC} -0.10	-	V	
•		$V_{CC} = 2.3 \text{ V}; \text{ V}_{I} = \text{V}_{IH} \text{ or } \text{V}_{IL}; \text{ I}_{O} = -8 \text{ mA}$	V _{CC} -0.28	-]		
		V_{CC} = 3.0 V; V_I = V_{IH} or V_{IL} ; I_O = -12 mA	V _{CC} -0.70	V _{CC} -0.32	-		
		V_{CC} = 1.65 to 3.6 V; V_{I} = V_{IH} or $V_{IL};$ I_{O} = 100 μA	-	GND	0.20		
V _{OL}	LOW level output voltage	V_{CC} = 1.65 V; V_I = V_{IH} or V_{IL} ; I_O = 4 mA	-	0.10	0.45	V	
		V_{CC} = 2.3 V; V_I = V_{IH} or V_{IL} ; I_O = 8 mA	-	0.26	0.55		
		V_{CC} = 3.0 V; V_I = V_{IH} or V_{IL} ; I_O = 12 mA	-	0.36	0.70		
lį	Input leakage current	V_{CC} = 1.65 to 3.6 V; $V_I = V_{CC}$ or GND	-	0.1	2.5	μA	
I _{OFF}	3-State output OFF-state current	V_{CC} = 0 V; V _I or V _O = 3.6 V	-	0.1	±10	μΑ	
I _{IHZ} /I _{ILZ}	3-State output OFF-state current	V_{CC} = 1.65 to 3.6 V; V_I = V_{CC} or GND	-	0.1	12.5	μA	
1	3-State output OFF-state current	V_{CC} = 1.65 to 2.7 V; V_I = V_{IH} or V_{IL} ; V_O = V_{CC} or GND	-	0.1	5		
I _{OZ}			-	0.1	10	μA	
1	Quiescent supply current	V_{CC} = 1.65 to 2.7 V; V_I = V_{CC} or GND; I_O = 0	-	0.1	20		
ICC	Quiescent supply current	$V_{CC} = 3.0$ to 3.6 V; $V_{I} = V_{CC}$ or GND; $I_{O} = 0$	-	0.2	40	μA	

NOTE:

1. All typical values are at T_{amb} = 25 $^\circ C.$

AC CHARACTERISTICS

GND = 0 V; t_r = t_f \leq 2.0 ns; C_L = 30 pF

			LIMITS													
SYMBOL PARAMETER		WAVEFORM	V_{CC} = 3.3 \pm 0.3 V			V_{CC} = 2.5 \pm 0.2 V			V_{CC} = 1.8 \pm 0.15 V			V _{CC} = 1.5 ± 0.1 V		V _{CC} = 1.5 V	V _{CC} = 1.2 V	UNIT
			MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	MIN	TYP ¹	MAX	MIN	MAX	TYP	TYP	1
	Propagation delay An to Yn	1, 7	0.9 0.7	1.7	2.6 2.5	1.0 0.8	2.0	3.2 3.0	1.5 1.0	2.8 2.6	4.9 4.5	2.0	5.8	3.6	5.9 5.2	
t _{PHL} /t _{PLH}	Propagation delay LE to Yn	2, 7	1.2 0.7	2.0 1.9	3.0 2.9	1.5 0.8	2.4 2.3	3.7 3.5	1.8 1.0	3.4 2.9	5.3	2.3	6.5	4.0	6.5 5.8	ns
	Propagation delay CP to Yn	3, 7	0.8 0.7	1.7	2.5	1.1 0.8	2.0	3.0	1.6 1.0	2.8 2.6	4.4 4.5	2.0	5.1	3.7	4.9 5.2	
t _{PZH} /t _{PZL}	3-State output enable time OE to Yn	6, 7	1.3 1.0	2.5 2.3	4.3 4.0	1.6 1.0	2.8 2.5	4.8 4.5	2.2 1.5	4.0 3.0	6.7 6.5	2.8	8.2	5.0	8.0 5.5	ns
t _{PHZ} /t _{PLZ}	3-State output disable time OE to Yn	6, 7	1.5 1.0	3.0 2.3	4.7 3.5	1.5 1.0	3.4 2.2	5.6 4.0	2.4 1.5	4.6 3.5	7.2 6.5	2.1	6.9	4.5	6.5 5.5	ns
+	CP pulse width HIGH or LOW	3, 7	1.0	-	-	1.2	-	-	2.0	-	-	-	-	-	-	ns
t _W	LE pulse width HIGH	2, 7	1.0	-	-	1.2	-	-	2.0	-	-	-	-	-	-	115
+	Set-up time An to CP	5, 7	0.3	-0.5	-	0.1	-0.2	-	0	-0.2	-	0.2	-	0	0	ns
ts∪	Set-up time An to LE	4, 7	0.5	0.1	-	0.6	0.1	-	1.0	0.5	-	1.5	-	0.8	1.5	115
	Hold time An to CP	5, 7	0.9	0.6	-	0.7	0.3	-	0.7	0.3	-	0.6	-	0.3	0.1	
t _h	Hold time An to LE	4, 7	0.6	0.4	-	0.2	0.1	-	0.1	0	-	0.1	-	0	-0.7	ns
f _{max}	Maximum clock pulse frequency	3, 7	500	-	-	400	-	-	250	-	-	-	-	-	-	MHz

NOTE:

1. All typical values are measured at T_{amb} = 25 $^{\circ}C$ and at V_{CC} = 1.8 V, 2.5 V, 3.3 V.

Product data

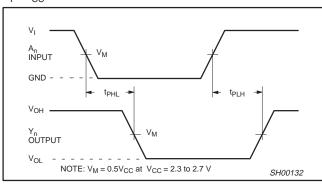
74AVC16834A

AC WAVEFORMS FOR V_{CC} = 3.0 V TO 3.6 V RANGE

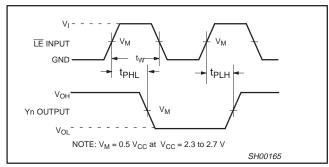
 $\begin{array}{l} V_M = 0.5 \ V_{CC} \\ V_X = V_{OL} + 0.300 \ V \\ V_Y = V_{OH} - 0.300 \ V \\ V_{OL} \ \text{and} \ V_{OH} \ \text{are the typical output voltage drop that occur with the output load.} \\ V_I = V_{CC} \end{array}$

AC WAVEFORMS FOR V_{CC} = 2.3 V TO 2.7 V AND V_{CC} < 2.3 V RANGE

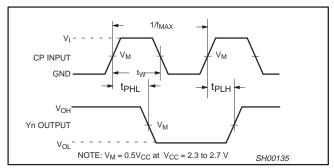
 $\label{eq:VM} \begin{array}{l} V_M = 0.5 \; V_{CC} \\ V_X = V_{OL} + 0.15 \; V \\ V_Y = V_{OH} - 0.15 \; V \\ V_{OL} \; \text{and} \; V_{OH} \; \text{are the typical output voltage drop that occur with the output load.} \\ V_I = V_{CC} \end{array}$



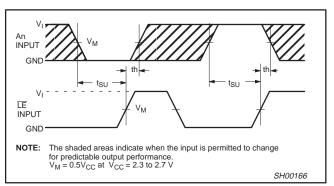
Waveform 1. Input (An) to output (Yn) propagation delay



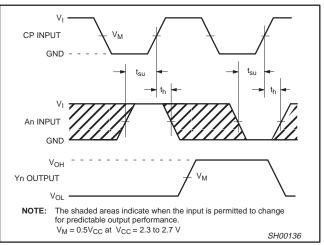
Waveform 2. Latch enable input (LE) pulse width, the latch enable input to output (Yn) propagation delays.



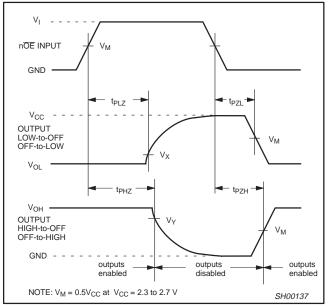
Waveform 3. The clock (CP) to Yn propagation delays, the clock pulse width and the maximum clock frequency.



Waveform 4. Data set-up and hold times for the An input to the LE input



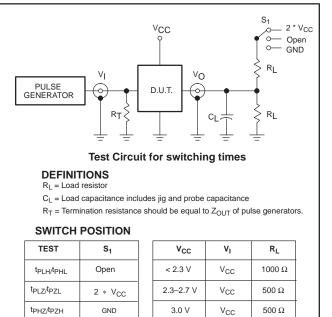
Waveform 5. Data set-up and hold times for the An input to the clock CP input



Waveform 6. 3-State enable and disable times

74AVC16834A

TEST CIRCUIT



Waveform 7. Load circuitry for switching times

SV01018

GRAPHS

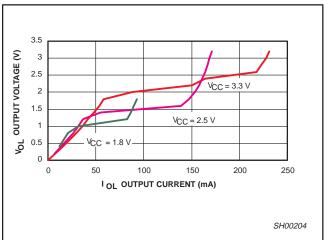


Figure 1. Output voltage (V_{OL}) vs. output current (I_{OL})

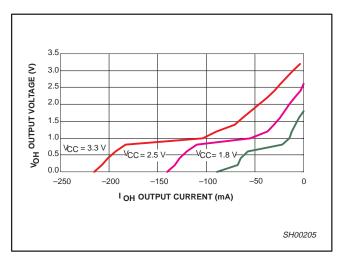
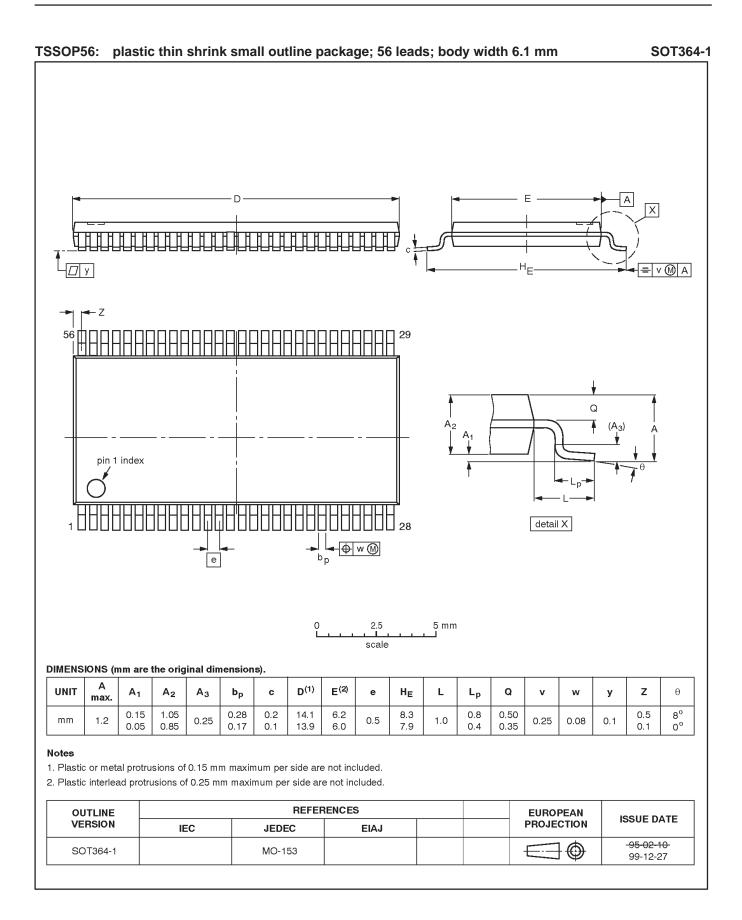
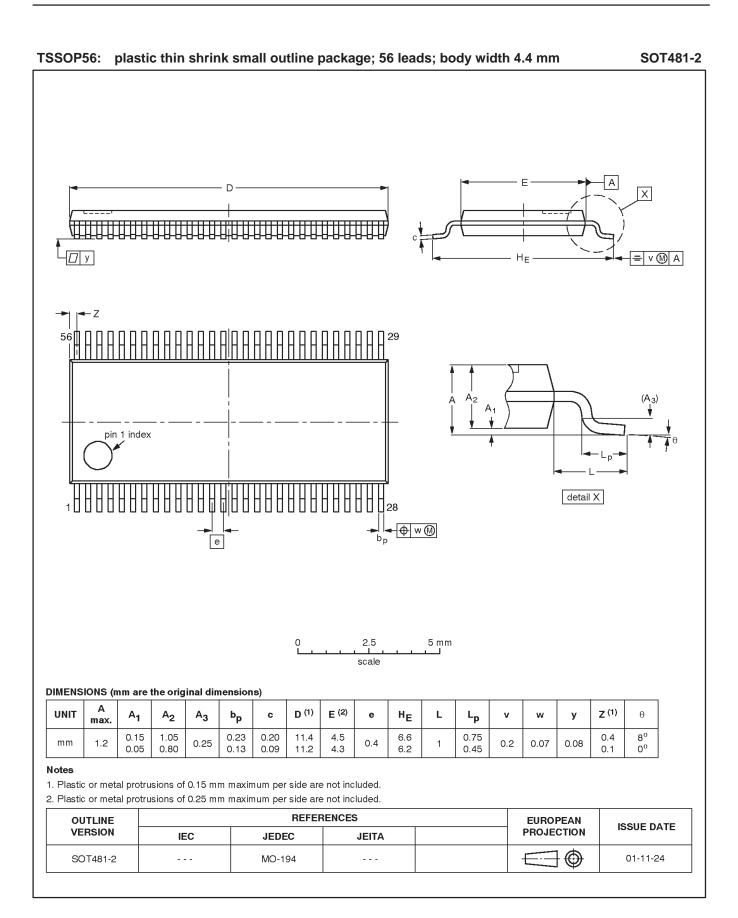


Figure 2. Output voltage (V_{OH}) vs. output current (I_{OH})

A Dynamic Controlled Output (DCO) circuit is designed in. During the transition, it initially lowers the output impedance to effectively drive the load and, subsequently, raises the impedance to reduce noise. Figures 1 and 2 show V_{OL} vs. I_{OL} and V_{OH} vs. I_{OH} curves to illustrate the output impedance and drive capability of the circuit. At the beginning of the signal transition, the DCO circuit provides a maximum dynamic drive that is equivalent to a high drive standard output device.





74AVC16834A

REVISION HISTORY

Rev	Date	Description
_4	2000 Jul 25	Product specification (9397 750 07353); fourth version. Engineering Change Notice: 853-2207 24201:
_5	2002 Sep 11	Product data (9397 750 10331); fifth version supersedes Product specification 2000 Jul 25. Engineering Change Notice: 853-2207 28874 (2002 Sep 09).
		Modifications: Add new package option (TVSOP) to existing product data sheet.

Product data

74AVC16834A

Data sheet status

Data sheet status ^[1]	Product status ^[2]	Definitions
Objective data	Development	This data sheet contains data from the objective specification for product development. Philips Semiconductors reserves the right to change the specification in any manner without notice.
Preliminary data	Qualification	This data sheet contains data from the preliminary specification. Supplementary data will be published at a later date. Philips Semiconductors reserves the right to change the specification without notice, in order to improve the design and supply the best possible product.
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[1] Please consult the most recently issued data sheet before initiating or completing a design.

[2] The product status of the device(s) described in this data sheet may have changed since this data sheet was published. The latest information is available on the Internet at URL http://www.semiconductors.philips.com.

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9397 750 10331

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